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#### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "[Embedded - Microcontrollers](#)"

##### Details

Product Status	Obsolete
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, EBI/EMI, I²C, IrDA, SPI, UART/USART, USB, USB OTG
Peripherals	DMA, I²S, LVD, POR, PWM, WDT
Number of I/O	-
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	81-LBGA
Supplier Device Package	81-MAPBGA (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mk20dx64vmb7">https://www.e-xfl.com/product-detail/nxp-semiconductors/mk20dx64vmb7</a>

### 3.3.1 Example

This is an example of an attribute:

Symbol	Description	Min.	Max.	Unit
CIN_D	Input capacitance: digital pins	—	7	pF

## 3.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

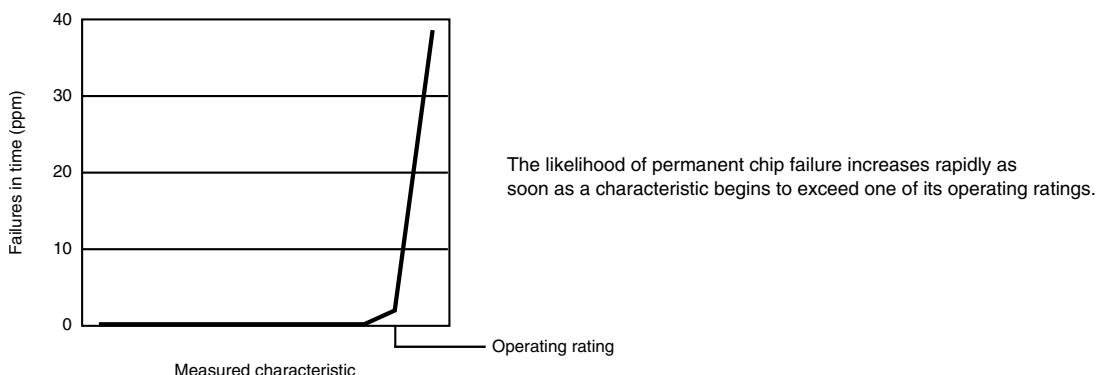
- *Operating ratings* apply during operation of the chip.
- *Handling ratings* apply when the chip is not powered.

### 3.4.1 Example

This is an example of an operating rating:

Symbol	Description	Min.	Max.	Unit
V <sub>DD</sub>	1.0 V core supply voltage	-0.3	1.2	V

## 3.5 Result of exceeding a rating



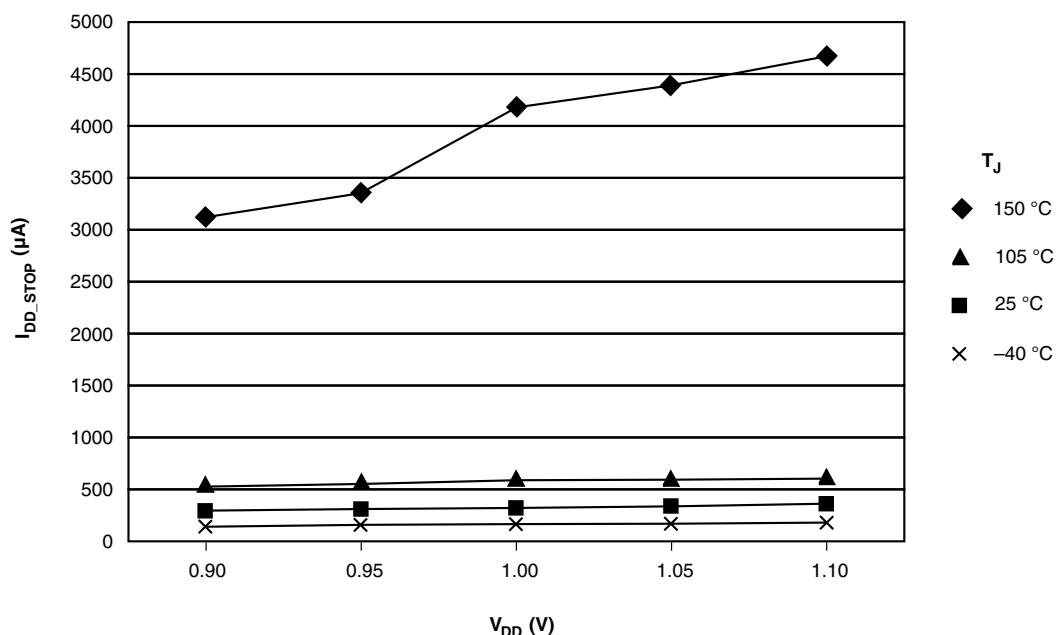
### 3.8.1 Example 1

This is an example of an operating behavior that includes a typical value:

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{WP}$	Digital I/O weak pullup/pulldown current	10	70	130	$\mu A$

### 3.8.2 Example 2

This is an example of a chart that shows typical values for various voltage and temperature conditions:



## 3.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
$T_A$	Ambient temperature	25	°C
$V_{DD}$	3.3 V supply voltage	3.3	V

## 4 Ratings

### 4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
$T_{STG}$	Storage temperature	-55	150	°C	<a href="#">1</a>
$T_{SDR}$	Solder temperature, lead-free	—	260	°C	<a href="#">2</a>

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

### 4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	<a href="#">1</a>

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

### 4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
$V_{HBM}$	Electrostatic discharge voltage, human body model	-2000	+2000	V	<a href="#">1</a>
$V_{CDM}$	Electrostatic discharge voltage, charged-device model	-500	+500	V	<a href="#">2</a>
$I_{LAT}$	Latch-up current at ambient temperature of 105°C	-100	+100	mA	

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.

### 4.4 Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
$V_{DD}$	Digital supply voltage	-0.3	3.8	V

Table continues on the next page...

## 5.2 Nonswitching electrical specifications

### 5.2.1 Voltage and current operating requirements

Table 1. Voltage and current operating requirements

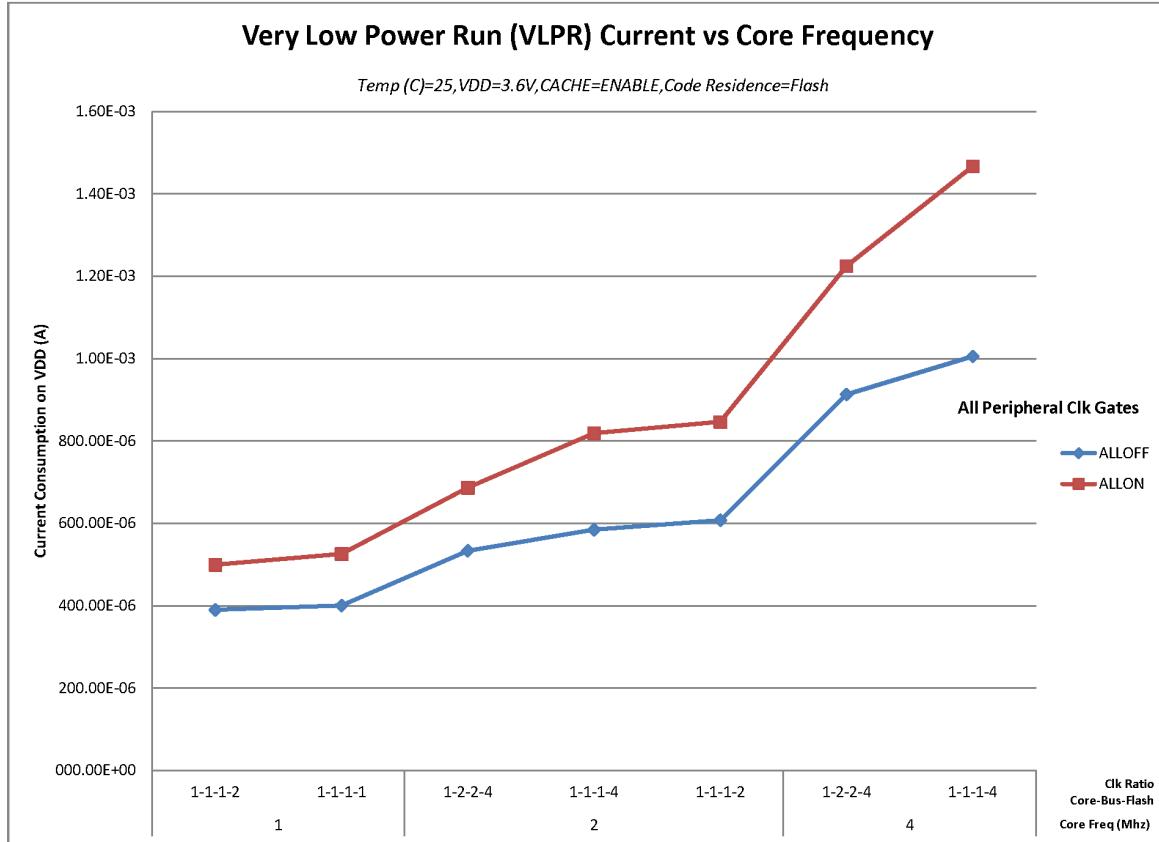
Symbol	Description	Min.	Max.	Unit	Notes
$V_{DD}$	Supply voltage	1.71	3.6	V	
$V_{DDA}$	Analog supply voltage	1.71	3.6	V	
$V_{DD} - V_{DDA}$	$V_{DD}$ -to- $V_{DDA}$ differential voltage	-0.1	0.1	V	
$V_{SS} - V_{SSA}$	$V_{SS}$ -to- $V_{SSA}$ differential voltage	-0.1	0.1	V	
$V_{BAT}$	RTC battery supply voltage	1.71	3.6	V	
$V_{IH}$	Input high voltage				
	• $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$	$0.7 \times V_{DD}$	—	V	
	• $1.7 \text{ V} \leq V_{DD} \leq 2.7 \text{ V}$	$0.75 \times V_{DD}$	—	V	
$V_{IL}$	Input low voltage				
	• $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$	—	$0.35 \times V_{DD}$	V	
	• $1.7 \text{ V} \leq V_{DD} \leq 2.7 \text{ V}$	—	$0.3 \times V_{DD}$	V	
$V_{HYS}$	Input hysteresis	$0.06 \times V_{DD}$	—	V	
$I_{ICDIO}$	Digital pin negative DC injection current — single pin	-5	—	mA	1
	• $V_{IN} < V_{SS}-0.3\text{V}$				
$I_{ICAIO}$	Analog <sup>2</sup> , EXTAL, and XTAL pin DC injection current — single pin			mA	3
	• $V_{IN} < V_{SS}-0.3\text{V}$ (Negative current injection)	-5	—		
	• $V_{IN} > V_{DD}+0.3\text{V}$ (Positive current injection)	—	+5		
$I_{ICcont}$	Contiguous pin DC injection current —regional limit, includes sum of negative injection currents or sum of positive injection currents of 16 contiguous pins			mA	
	• Negative current injection	-25	—		
	• Positive current injection	—	+25		
$V_{RAM}$	$V_{DD}$ voltage required to retain RAM	1.2	—	V	
$V_{RFVBAT}$	$V_{BAT}$ voltage required to retain the VBAT register file	$V_{POR\_VBAT}$	—	V	

1. All 5 V tolerant digital I/O pins are internally clamped to  $V_{SS}$  through a ESD protection diode. There is no diode connection to  $V_{DD}$ . If  $V_{IN}$  greater than  $V_{DIO\_MIN}$  ( $=V_{SS}-0.3\text{V}$ ) is observed, then there is no need to provide current limiting resistors at the pads. If this limit cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as  $R=(V_{DIO\_MIN}-V_{IN})/|I_{IC}|$ .
2. Analog pins are defined as pins that do not have an associated general purpose I/O port function.

**Table 6. Power consumption operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I <sub>DD_VLPR</sub>	Very-low-power run mode current at 3.0 V — all peripheral clocks enabled	—	1.46	—	mA	7
I <sub>DD_VLPW</sub>	Very-low-power wait mode current at 3.0 V — all peripheral clocks disabled	—	0.61	—	mA	8
I <sub>DD_STOP</sub>	Stop mode current at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	0.35 0.384 0.628	0.567 0.793 1.2	mA mA mA	
I <sub>DD_VLPS</sub>	Very-low-power stop mode current at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	5.9 26.1 98.1	32.7 59.8 188	μA μA μA	
I <sub>DD_LLS</sub>	Low leakage stop mode current at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	2.6 10.3 42.5	8.6 29.1 92.5	μA μA μA	9
I <sub>DD_VLLS3</sub>	Very low-leakage stop mode 3 current at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	1.9 6.9 28.1	5.8 12.1 41.9	μA μA μA	9
I <sub>DD_VLLS2</sub>	Very low-leakage stop mode 2 current at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	1.59 4.3 17.5	5.5 9.5 34	μA μA μA	
I <sub>DD_VLLS1</sub>	Very low-leakage stop mode 1 current at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	1.47 2.97 12.41	5.4 8.1 32	μA μA μA	
I <sub>DD_VBAT</sub>	Average current with RTC and 32kHz disabled at 3.0 V • @ -40 to 25°C • @ 70°C • @ 105°C	— — —	0.19 0.49 2.2	0.22 0.64 3.2	μA μA μA	

Table continues on the next page...



**Figure 3. VLPR mode supply current vs. core frequency**

### 5.2.6 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

1. Go to <http://www.freescale.com>.
2. Perform a keyword search for “EMC design.”

### 5.2.7 Capacitance attributes

**Table 7. Capacitance attributes**

Symbol	Description	Min.	Max.	Unit
$C_{IN\_A}$	Input capacitance: analog pins	—	7	pF

*Table continues on the next page...*

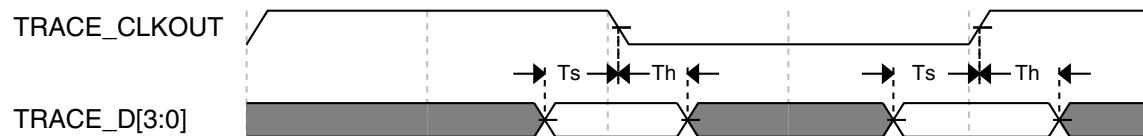


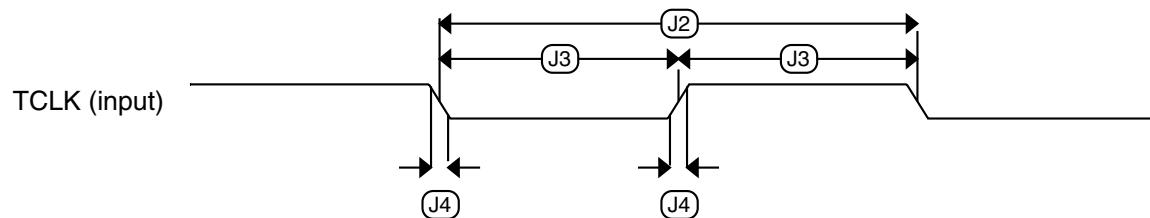
Figure 5. Trace data specifications

### 6.1.2 JTAG electricals

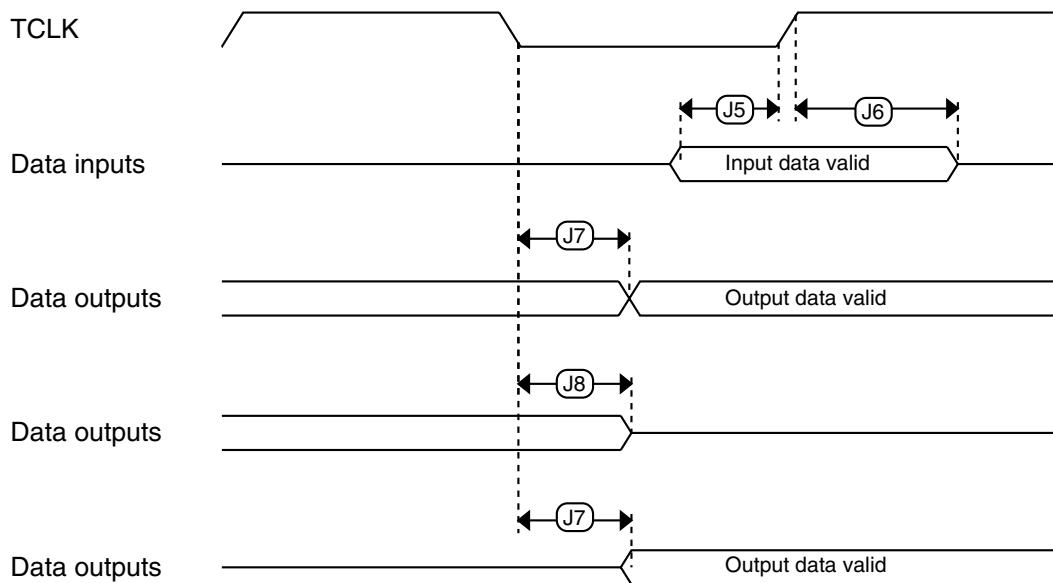
Table 12. JTAG voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	2.7	5.5	V
J1	TCLK frequency of operation <ul style="list-style-type: none"> <li>• JTAG</li> <li>• CJTAG</li> </ul>	—	10	MHz
		—	5	
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width <ul style="list-style-type: none"> <li>• JTAG</li> <li>• CJTAG</li> </ul>	100 200	— —	ns ns ns
J4	TCLK rise and fall times	—	1	ns
J5	TMS input data setup time to TCLK rise <ul style="list-style-type: none"> <li>• JTAG</li> <li>• CJTAG</li> </ul>	53 112	— —	ns
J6	TDI input data setup time to TCLK rise	8	—	ns
J7	TMS input data hold time after TCLK rise <ul style="list-style-type: none"> <li>• JTAG</li> <li>• CJTAG</li> </ul>	3.4 3.4	— —	ns
J8	TDI input data hold time after TCLK rise	3.4	—	ns
J9	TCLK low to TMS data valid <ul style="list-style-type: none"> <li>• JTAG</li> <li>• CJTAG</li> </ul>	— —	48 85	ns
J10	TCLK low to TDO data valid	—	48	ns
J11	Output data hold/invalid time after clock edge <sup>1</sup>	—	3	ns

1. They are common for JTAG and CJTAG. Input transition = 1 ns and Output load = 50pf



**Figure 6. Test clock input timing**



**Figure 7. Boundary scan (JTAG) timing**

### 6.3.1 MCG specifications

Table 13. MCG specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$f_{ints\_ft}$	Internal reference frequency (slow clock) — factory trimmed at nominal VDD and 25 °C	—	32.768	—	kHz	
$f_{ints\_t}$	Internal reference frequency (slow clock) — user trimmed	31.25	—	39.0625	kHz	
$\Delta f_{dco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM and SCFTRIM	—	± 0.3	± 0.6	% $f_{dco}$	1
$\Delta f_{dco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM only	—	± 0.2	± 0.5	% $f_{dco}$	1
$\Delta f_{dco\_t}$	Total deviation of trimmed average DCO output frequency over voltage and temperature	—	+0.5/-0.7	—	% $f_{dco}$	1
$\Delta f_{dco\_t}$	Total deviation of trimmed average DCO output frequency over fixed voltage and temperature range of 0–70°C	—			% $f_{dco}$	1
$f_{intf\_ft}$	Internal reference frequency (fast clock) — factory trimmed at nominal VDD and 25°C	—	4	—	MHz	
$f_{intf\_t}$	Internal reference frequency (fast clock) — user trimmed at nominal VDD and 25 °C	3	—	5	MHz	
$f_{loc\_low}$	Loss of external clock minimum frequency — RANGE = 00	(3/5) × $f_{ints\_t}$	—	—	kHz	
$f_{loc\_high}$	Loss of external clock minimum frequency — RANGE = 01, 10, or 11	(16/5) × $f_{ints\_t}$	—	—	kHz	
<b>FLL</b>						
$f_{fill\_ref}$	FLL reference frequency range	31.25	—	39.0625	kHz	
$f_{dco}$	DCO output frequency range	Low range (DRS=00) 640 × $f_{fill\_ref}$	20	20.97	25	MHz
		Mid range (DRS=01) 1280 × $f_{fill\_ref}$	40	41.94	50	MHz
		Mid-high range (DRS=10) 1920 × $f_{fill\_ref}$	60	62.91	75	MHz
		High range (DRS=11) 2560 × $f_{fill\_ref}$	80	83.89	100	MHz

Table continues on the next page...

**Table 19. Flash command timing specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{pgmchk}$	Program Check execution time	—	—	45	μs	1
$t_{rdsrc}$	Read Resource execution time	—	—	30	μs	1
$t_{pgm4}$	Program Longword execution time	—	65	145	μs	
$t_{ersblk32k}$	Erase Flash Block execution time	—	55	465	ms	2
$t_{ersblk256k}$	• 32 KB data flash • 256 KB program flash	—	122	985	ms	
$t_{ersscr}$	Erase Flash Sector execution time	—	14	114	ms	2
$t_{pgmsec512p}$	Program Section execution time	—	2.4	—	ms	
$t_{pgmsec512d}$	• 512 B program flash	—	4.7	—	ms	
$t_{pgmsec1kp}$	• 512 B data flash	—	4.7	—	ms	
$t_{pgmsec1kd}$	• 1 KB program flash • 1 KB data flash	—	9.3	—	ms	
$t_{rd1all}$	Read 1s All Blocks execution time	—	—	1.8	ms	
$t_{rdonce}$	Read Once execution time	—	—	25	μs	1
$t_{pgmonce}$	Program Once execution time	—	65	—	μs	
$t_{ersall}$	Erase All Blocks execution time	—	175	1500	ms	2
$t_{vfkey}$	Verify Backdoor Access Key execution time	—	—	30	μs	1
$t_{swapx01}$	Swap Control execution time	—	200	—	μs	
$t_{swapx02}$	• control code 0x01	—	70	150	μs	
$t_{swapx04}$	• control code 0x02	—	70	150	μs	
$t_{swapx08}$	• control code 0x04 • control code 0x08	—	—	30	μs	
$t_{pgmpart32k}$	Program Partition for EEPROM execution time	—	70	—	ms	
$t_{pgmpart32k}$	• 32 KB FlexNVM	—	—	—	ms	
$t_{setramff}$	Set FlexRAM Function execution time:	—	50	—	μs	
$t_{setram8k}$	• Control Code 0xFF	—	0.3	0.5	ms	
$t_{setram32k}$	• 8 KB EEPROM backup • 32 KB EEPROM backup	—	0.7	1.0	ms	
Byte-write to FlexRAM for EEPROM operation						
$t_{eewr8bers}$	Byte-write to erased FlexRAM location execution time	—	175	260	μs	3

Table continues on the next page...

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the Flexbus output clock (FB\_CLK). All other timing relationships can be derived from these values.

**Table 23. Flexbus limited voltage range switching specifications**

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	20	—	ns	
FB2	Address, data, and control output valid	—	11.5	ns	<a href="#">1</a>
FB3	Address, data, and control output hold	0.5	—	ns	<a href="#">1</a>
FB4	Data and $\overline{\text{FB\_TA}}$ input setup	8.5	—	ns	<a href="#">2</a>
FB5	Data and $\overline{\text{FB\_TA}}$ input hold	0.5	—	ns	<a href="#">2</a>

1. Specification is valid for all FB\_AD[31:0],  $\overline{\text{FB\_BE/BWEn}}$ ,  $\overline{\text{FB\_CSn}}$ ,  $\overline{\text{FB\_OE}}$ , FB\_R/W,  $\overline{\text{FB\_TBST}}$ , FB\_TSIZ[1:0], FB\_ALE, and  $\overline{\text{FB\_TS}}$ .
2. Specification is valid for all FB\_AD[31:0] and  $\overline{\text{FB\_TA}}$ .

**Table 24. Flexbus full voltage range switching specifications**

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	
	Frequency of operation	—	FB_CLK	MHz	
FB1	Clock period	1/FB_CLK	—	ns	
FB2	Address, data, and control output valid	—	13.5	ns	<a href="#">1</a>
FB3	Address, data, and control output hold	0	—	ns	<a href="#">1</a>
FB4	Data and $\overline{\text{FB\_TA}}$ input setup	13.7	—	ns	<a href="#">2</a>
FB5	Data and $\overline{\text{FB\_TA}}$ input hold	0.5	—	ns	<a href="#">2</a>

1. Specification is valid for all FB\_AD[31:0],  $\overline{\text{FB\_BE/BWEn}}$ ,  $\overline{\text{FB\_CSn}}$ ,  $\overline{\text{FB\_OE}}$ , FB\_R/W,  $\overline{\text{FB\_TBST}}$ , FB\_TSIZ[1:0], FB\_ALE, and  $\overline{\text{FB\_TS}}$ .
2. Specification is valid for all FB\_AD[31:0] and  $\overline{\text{FB\_TA}}$ .

**6.6.1.2 16-bit ADC electrical characteristics****Table 26. 16-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
$I_{DDA\_ADC}$	Supply current		0.215	—	1.7	mA	<sup>3</sup>
$f_{ADACK}$	ADC asynchronous clock source	<ul style="list-style-type: none"> <li>• ADLPC=1, ADHSC=0</li> <li>• ADLPC=1, ADHSC=1</li> <li>• ADLPC=0, ADHSC=0</li> <li>• ADLPC=0, ADHSC=1</li> </ul>	1.2 3.0 2.4 4.4	2.4 4.0 5.2 6.2	3.9 7.3 6.1 9.5	MHz MHz MHz MHz	$t_{ADACK} = 1/f_{ADACK}$
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	<ul style="list-style-type: none"> <li>• 12 bit modes</li> <li>• &lt;12 bit modes</li> </ul>	— —	$\pm 4$ $\pm 1.4$	$\pm 6.8$ $\pm 2.1$	LSB <sup>4</sup>	<sup>5</sup>
DNL	Differential non-linearity	<ul style="list-style-type: none"> <li>• 12 bit modes</li> <li>• &lt;12 bit modes</li> </ul>	— —	$\pm 0.7$ $\pm 0.2$	-1.1 to +1.9 -0.3 to 0.5	LSB <sup>4</sup>	<sup>5</sup>
INL	Integral non-linearity	<ul style="list-style-type: none"> <li>• 12 bit modes</li> <li>• &lt;12 bit modes</li> </ul>	— —	$\pm 1.0$ $\pm 0.5$	-2.7 to +1.9 -0.7 to +0.5	LSB <sup>4</sup>	<sup>5</sup>
$E_{FS}$	Full-scale error	<ul style="list-style-type: none"> <li>• 12 bit modes</li> <li>• &lt;12 bit modes</li> </ul>	— —	-4 -1.4	-5.4 -1.8	LSB <sup>4</sup>	$V_{ADIN} = V_{DDA}$ <sup>5</sup>
$E_Q$	Quantization error	<ul style="list-style-type: none"> <li>• 16 bit modes</li> <li>• ≤13 bit modes</li> </ul>	— —	-1 to 0 —	— $\pm 0.5$	LSB <sup>4</sup>	
ENOB	Effective number of bits	16 bit differential mode <ul style="list-style-type: none"> <li>• Avg=32</li> <li>• Avg=4</li> </ul> 16 bit single-ended mode <ul style="list-style-type: none"> <li>• Avg=32</li> <li>• Avg=4</li> </ul>	12.8 11.9 12.2 11.4	14.5 13.8 13.9 13.1	— — — —	bits bits bits bits	<sup>6</sup>
SINAD	Signal-to-noise plus distortion	See ENOB	$6.02 \times ENOB + 1.76$			dB	
THD	Total harmonic distortion	16 bit differential mode <ul style="list-style-type: none"> <li>• Avg=32</li> </ul> 16 bit single-ended mode <ul style="list-style-type: none"> <li>• Avg=32</li> </ul>	— —	-94 -85	— —	dB dB	<sup>7</sup>

Table continues on the next page...

### 6.6.1.3 16-bit ADC with PGA operating conditions

Table 27. 16-bit ADC with PGA operating conditions

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
$V_{DDA}$	Supply voltage	Absolute	1.71	—	3.6	V	
$V_{REFPGA}$	PGA ref voltage		$V_{REF\_OUT}$	$V_{REF\_OUT}$	$V_{REF\_OUT}$	V	<sup>2, 3</sup>
$V_{ADIN}$	Input voltage		$V_{SSA}$	—	$V_{DDA}$	V	
$V_{CM}$	Input Common Mode range		$V_{SSA}$	—	$V_{DDA}$	V	
$R_{PGAD}$	Differential input impedance	Gain = 1, 2, 4, 8	—	128	—	kΩ	IN+ to IN- <sup>4</sup>
		Gain = 16, 32	—	64	—		
		Gain = 64	—	32	—		
$R_{AS}$	Analog source resistance		—	100	—	Ω	<sup>5</sup>
$T_S$	ADC sampling time		1.25	—	—	μs	<sup>6</sup>
$C_{rate}$	ADC conversion rate	≤ 13 bit modes No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz	18.484	—	450	Ksps	<sup>7</sup>
		16 bit modes No ADC hardware averaging Continuous conversions enabled Peripheral clock = 50 MHz	37.037	—	250	Ksps	<sup>8</sup>

1. Typical values assume  $V_{DDA} = 3.0$  V, Temp = 25°C,  $f_{ADCK} = 6$  MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. ADC must be configured to use the internal voltage reference (VREF\_OUT)
3. PGA reference is internally connected to the VREF\_OUT pin. If the user wishes to drive VREF\_OUT with a voltage other than the output of the VREF module, the VREF module must be disabled.
4. For single ended configurations the input impedance of the driven input is  $R_{PGAD}/2$
5. The analog source resistance ( $R_{AS}$ ), external to MCU, should be kept as minimum as possible. Increased  $R_{AS}$  causes drop in PGA gain without affecting other performances. This is not dependent on ADC clock frequency.
6. The minimum sampling time is dependent on input signal frequency and ADC mode of operation. A minimum of 1.25μs time should be allowed for  $F_{in}=4$  kHz at 16-bit differential mode. Recommended ADC setting is: ADLSMP=1, ADLSTS=2 at 8 MHz ADC clock.
7. ADC clock = 18 MHz, ADLSMP = 1, ADLST = 00, ADHSC = 1
8. ADC clock = 12 MHz, ADLSMP = 1, ADLST = 01, ADHSC = 1

## 6.6.2 CMP and 6-bit DAC electrical specifications

Table 29. Comparator and 6-bit DAC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
$V_{DD}$	Supply voltage	1.71	—	3.6	V
$I_{DDHS}$	Supply current, High-speed mode (EN=1, PMODE=1)	—	—	200	$\mu A$
$I_{DDLS}$	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	$\mu A$
$V_{AIN}$	Analog input voltage	$V_{SS} - 0.3$	—	$V_{DD}$	V
$V_{AIO}$	Analog input offset voltage	—	—	20	mV
$V_H$	Analog comparator hysteresis <sup>1</sup>	—	5	—	mV
	• CR0[HYSTCTR] = 00	—	10	—	mV
	• CR0[HYSTCTR] = 01	—	20	—	mV
	• CR0[HYSTCTR] = 10	—	30	—	mV
$V_{CMPOh}$	Output high	$V_{DD} - 0.5$	—	—	V
	Output low	—	—	0.5	V
$t_{DHS}$	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
$t_{DLS}$	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns
Analog comparator initialization delay <sup>2</sup>		—	—	40	$\mu s$
$I_{DAC6b}$	6-bit DAC current adder (enabled)	—	7	—	$\mu A$
INL	6-bit DAC integral non-linearity	-0.5	—	0.5	LSB <sup>3</sup>
DNL	6-bit DAC differential non-linearity	-0.3	—	0.3	LSB

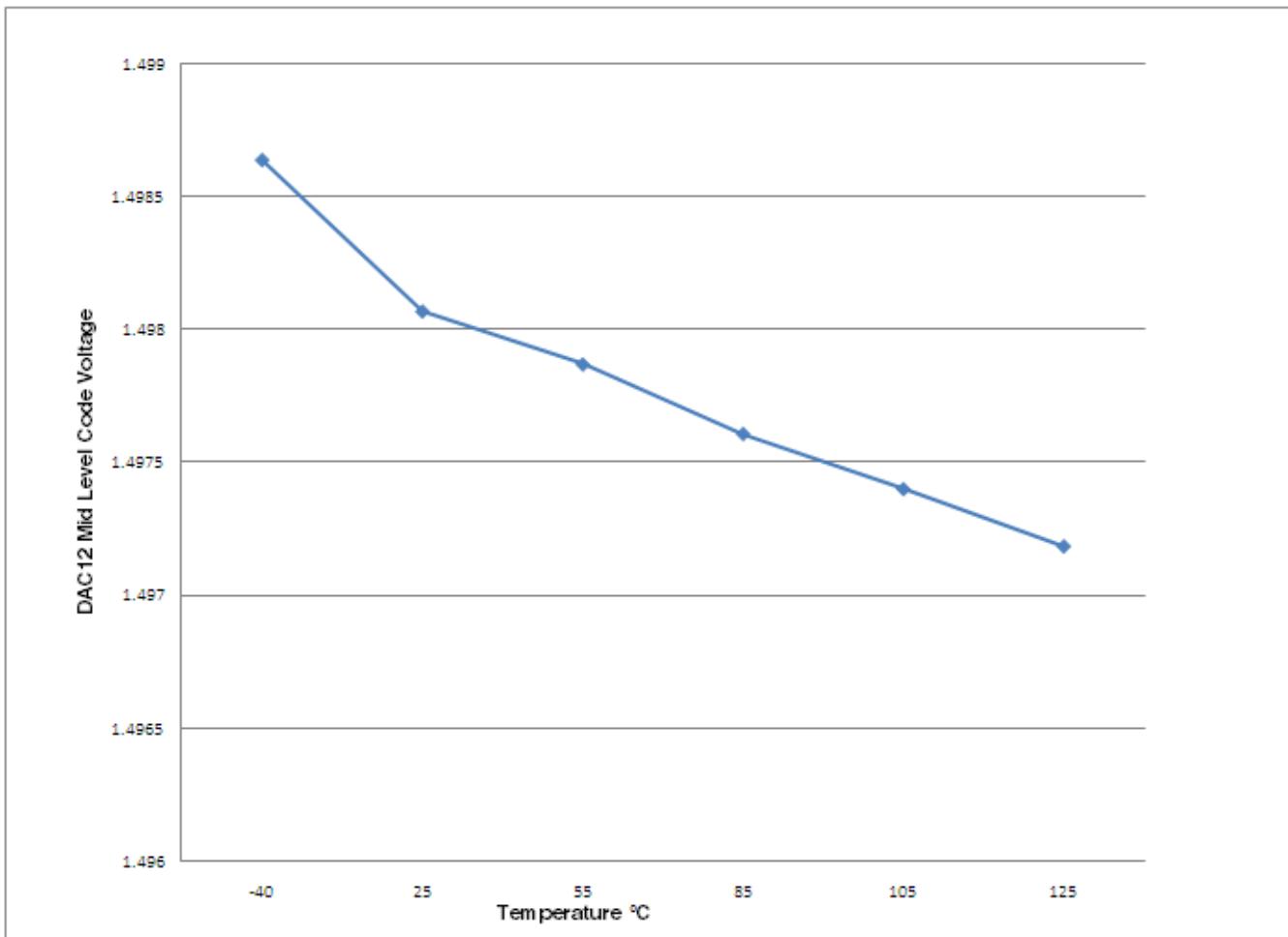
1. Typical hysteresis is measured with input voltage range limited to 0.6 to  $V_{DD}-0.6V$ .
2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to DACEN, VRSEL, PSEL, MSEL, VOSEL) and the comparator output settling to a stable level.
3. 1 LSB =  $V_{reference}/64$

### 6.6.3.2 12-bit DAC operating behaviors

Table 31. 12-bit DAC operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I <sub>DDA_DACL_P</sub>	Supply current — low-power mode	—	—	150	μA	
I <sub>DDA_DAC_HP</sub>	Supply current — high-speed mode	—	—	700	μA	
t <sub>DACLP</sub>	Full-scale settling time (0x080 to 0xF7F) — low-power mode	—	100	200	μs	1
t <sub>DACHP</sub>	Full-scale settling time (0x080 to 0xF7F) — high-power mode	—	15	30	μs	1
t <sub>CCDACL_P</sub>	Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode	—	0.7	1	μs	1
V <sub>dacoutl</sub>	DAC output voltage range low — high-speed mode, no load, DAC set to 0x000	—	—	100	mV	
V <sub>dacouth</sub>	DAC output voltage range high — high-speed mode, no load, DAC set to 0xFFFF	V <sub>DACR</sub> –100	—	V <sub>DACR</sub>	mV	
INL	Integral non-linearity error — high speed mode	—	—	±8	LSB	2
DNL	Differential non-linearity error — V <sub>DACR</sub> > 2 V	—	—	±1	LSB	3
DNL	Differential non-linearity error — V <sub>DACR</sub> = VREF_OUT	—	—	±1	LSB	4
V <sub>OFFSET</sub>	Offset error	—	±0.4	±0.8	%FSR	5
E <sub>G</sub>	Gain error	—	±0.1	±0.6	%FSR	5
PSRR	Power supply rejection ratio, V <sub>DDA</sub> > = 2.4 V	60	—	90	dB	
T <sub>CO</sub>	Temperature coefficient offset voltage	—	3.7	—	μV/C	6
T <sub>GE</sub>	Temperature coefficient gain error	—	0.000421	—	%FSR/C	
R <sub>op</sub>	Output resistance load = 3 kΩ	—	—	250	Ω	
SR	Slew rate -80h → F7Fh → 80h • High power (SP <sub>HP</sub> ) • Low power (SP <sub>LP</sub> )	1.2 0.05	1.7 0.12	— —	V/μs	
CT	Channel to channel cross talk	—	—	-80	dB	
BW	3dB bandwidth • High power (SP <sub>HP</sub> ) • Low power (SP <sub>LP</sub> )	550 40	— —	— —	kHz	

- Settling within ±1 LSB
- The INL is measured for 0+100mV to V<sub>DACR</sub>–100 mV
- The DNL is measured for 0+100 mV to V<sub>DACR</sub>–100 mV
- The DNL is measured for 0+100mV to V<sub>DACR</sub>–100 mV with V<sub>DDA</sub> > 2.4V
- Calculated by a best fit curve from V<sub>SS</sub>+100 mV to V<sub>DACR</sub>–100 mV

**Figure 20. Offset at half scale vs. temperature**

### 6.6.4 Voltage reference electrical specifications

**Table 32. VREF full-range operating requirements**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DDA}$	Supply voltage	1.71	3.6	V	
$T_A$	Temperature	-40	105	°C	
$C_L$	Output load capacitance		100	nF	1, 2

1.  $C_L$  must be connected to VREF\_OUT if the VREF\_OUT functionality is being used for either an internal or external reference.
2. The load capacitance should not exceed +/-25% of the nominal specified  $C_L$  value over the operating temperature range of the device.

**Table 38. USB VREG electrical specifications  
(continued)**

Symbol	Description	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
I <sub>LOAD</sub> stby	Maximum load current — Standby mode	—	—	1	mA	
V <sub>Reg33out</sub>	Regulator output voltage — Input supply (VREGIN) > 3.6 V • Run mode • Standby mode	3 2.1	3.3 2.8	3.6 3.6	V V	<sup>2</sup>
V <sub>Reg33out</sub>	Regulator output voltage — Input supply (VREGIN) < 3.6 V, pass-through mode	2.1	—	3.6	V	<sup>2</sup>
C <sub>OUT</sub>	External output capacitor	1.76	2.2	8.16	μF	
ESR	External output capacitor equivalent series resistance	1	—	100	mΩ	
I <sub>LIM</sub>	Short circuit current	—	290	—	mA	

1. Typical values assume VREGIN = 5.0 V, Temp = 25 °C unless otherwise stated.
2. Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I<sub>Load</sub>.

## 6.8.4 CAN switching specifications

See [General switching specifications](#).

## 6.8.5 DSPI switching specifications (limited voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

**Table 39. Master mode DSPI timing (limited voltage range)**

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	2.7	3.6	V	
	Frequency of operation	—	25	MHz	
DS1	DSPI_SCK output cycle time	2 × t <sub>BUS</sub>	—	ns	
DS2	DSPI_SCK output high/low time	(t <sub>SCK</sub> /2) – 2	(t <sub>SCK</sub> /2) + 2	ns	
DS3	DSPI_PCSn valid to DSPI_SCK delay	(t <sub>BUS</sub> × 2) – 2	—	ns	<sup>1</sup>

Table continues on the next page...

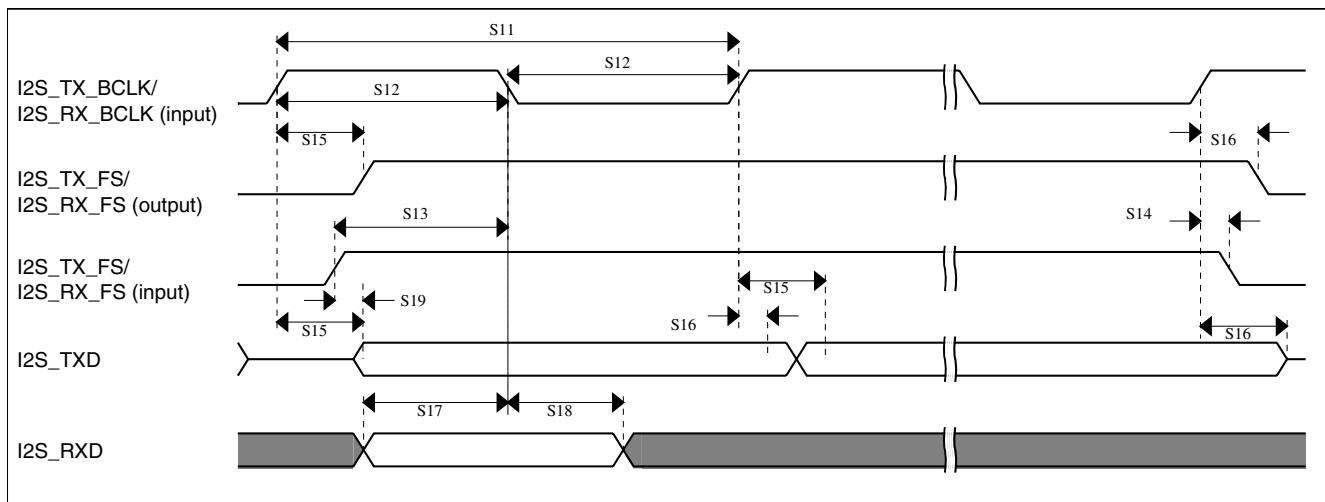


Figure 28. I2S/SAI timing — slave modes

## 6.9 Human-machine interfaces (HMI)

### 6.9.1 TSI electrical specifications

Table 47. TSI electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$V_{DDTSI}$	Operating voltage	1.71	—	3.6	V	
$C_{ELE}$	Target electrode capacitance range	1	20	500	pF	1
$f_{REFmax}$	Reference oscillator frequency	—	8	15	MHz	2, 3
$f_{ELEmax}$	Electrode oscillator frequency	—	1	1.8	MHz	2, 4
$C_{REF}$	Internal reference capacitor	—	1	—	pF	
$V_{\Delta}$	Oscillator delta voltage	—	500	—	mV	2, 5
$I_{REF}$	Reference oscillator current source base current <ul style="list-style-type: none"> <li>• 2 <math>\mu</math>A setting (REFCHRG = 0)</li> <li>• 32 <math>\mu</math>A setting (REFCHRG = 15)</li> </ul>	—	2	3	$\mu$ A	2, 6
$I_{ELE}$	Electrode oscillator current source base current <ul style="list-style-type: none"> <li>• 2 <math>\mu</math>A setting (EXTCHRG = 0)</li> <li>• 32 <math>\mu</math>A setting (EXTCHRG = 15)</li> </ul>	—	36	50	$\mu$ A	2, 7
Pres5	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	8
Pres20	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	9
Pres100	Electrode capacitance measurement precision	—	8.3333	38400	fF/count	10
MaxSens	Maximum sensitivity	0.003	12.5	—	fF/count	11
Res	Resolution	—	—	16	bits	

Table continues on the next page...

81 MAP BGA	80 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
K5	22	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23	DAC0_OUT/ CMP1_IN3/ ADC0_SE23								
L7	—	RTC_ WAKEUP_B	RTC_ WAKEUP_B	RTC_ WAKEUP_B								
L4	23	XTAL32	XTAL32	XTAL32								
L5	24	EXTAL32	EXTAL32	EXTAL32								
K6	25	VBAT	VBAT	VBAT								
J6	26	PTA0	JTAG_TCLK/ SWD_CLK/ EZP_CLK	TSI0_CH1	PTA0	UART0_CTS_ b/ UART0_COL_ b	FTM0_CH5				JTAG_TCLK/ SWD_CLK	EZP_CLK
H8	27	PTA1	JTAG_TDI/ EZP_DI	TSI0_CH2	PTA1	UART0_RX	FTM0_CH6				JTAG_TDI	EZP_DI
J7	28	PTA2	JTAG_TDO/ TRACE_SWO/ EZP_DO	TSI0_CH3	PTA2	UART0_TX	FTM0_CH7				JTAG_TDO/ TRACE_SWO	EZP_DO
H9	29	PTA3	JTAG_TMS/ SWD_DIO	TSI0_CH4	PTA3	UART0_RTS_ b	FTM0_CH0				JTAG_TMS/ SWD_DIO	
J8	30	PTA4/ LLWU_P3	NMI_b/ EZP_CS_b	TSI0_CH5	PTA4/ LLWU_P3		FTM0_CH1				NMI_b	EZP_CS_b
K7	31	PTA5	DISABLED		PTA5	USB_CLKIN	FTM0_CH2		CMP2_OUT	I2S0_TX_ BCLK	JTAG_TRST_ b	
E5	—	VDD	VDD	VDD								
G3	—	VSS	VSS	VSS								
K8	32	PTA12	CMP2_IN0	CMP2_IN0	PTA12	CAN0_TX	FTM1_CH0			I2S0_TXD0	FTM1_QD_ PHA	
L8	33	PTA13/ LLWU_P4	CMP2_IN1	CMP2_IN1	PTA13/ LLWU_P4	CAN0_RX	FTM1_CH1			I2S0_TX_FS	FTM1_QD_ PHB	
K9	34	PTA14	DISABLED		PTA14	SPI0_PCS0	UART0_TX			I2S0_RX_ BCLK	I2S0_RXD1	
L9	35	PTA15	DISABLED		PTA15	SPI0_SCK	UART0_RX			I2S0_RXD0		
J10	36	PTA16	DISABLED		PTA16	SPI0_SOUT	UART0_CTS_ b/ UART0_COL_ b			I2S0_RX_FS	I2S0_RXD1	
H10	37	PTA17	ADC1_SE17	ADC1_SE17	PTA17	SPI0_SIN	UART0_RTS_ b			I2S0_MCLK		
L10	38	VDD	VDD	VDD								
K10	39	VSS	VSS	VSS								
L11	40	PTA18	EXTAL0	EXTAL0	PTA18		FTM0_FLT2	FTM_CLKIN0				
K11	41	PTA19	XTAL0	XTAL0	PTA19		FTM1_FLT0	FTM_CLKIN1		LPTMR0_ ALT1		
J11	42	RESET_b	RESET_b	RESET_b								
G11	43	PTB0/ LLWU_P5	ADC0_SE8/ ADC1_SE8/ TSI0_CH0	ADC0_SE8/ ADC1_SE8/ TSI0_CH0	PTB0/ LLWU_P5	I2C0_SCL	FTM1_CH0			FTM1_QD_ PHA		

## Pinout

81 MAP BGA	80 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
F11	—	NC	NC	NC								
E11	—	NC	NC	NC								
D11	—	NC	NC	NC								
E10	—	NC	NC	NC								
F10	—	NC	NC	NC								
F9	—	NC	NC	NC								
F8	—	NC	NC	NC								
E8	—	NC	NC	NC								
B6	—	NC	NC	NC								
A6	—	NC	NC	NC								
A5	—	NC	NC	NC								
B5	—	NC	NC	NC								
B4	—	NC	NC	NC								
A4	—	NC	NC	NC								
A10	—	NC	NC	NC								
A9	—	NC	NC	NC								
B1	—	NC	NC	NC								
C2	—	NC	NC	NC								
C1	—	NC	NC	NC								
D2	—	NC	NC	NC								
D1	—	NC	NC	NC								
E1	—	NC	NC	NC								

## 8.2 K20 Pinouts

The below figure shows the pinout diagram for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, see the previous section.